# imall

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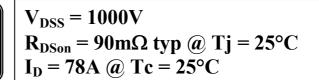
## Contact us

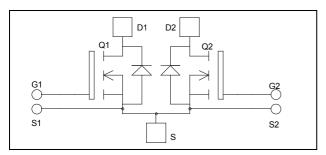
Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

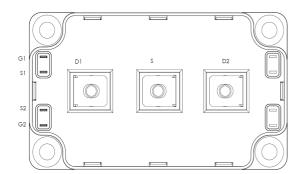




Dual Common Source MOSFET Power Module







#### Application

- AC Switches
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

#### Features

- Power MOS 7<sup>®</sup> MOSFETs
  - Low R<sub>DSon</sub>
    - Low input and Miller capacitance
    - Low gate charge
    - Avalanche energy rated
  - Very rugged
  - Kelvin source for easy drive
    - Very low stray inductance
      - Symmetrical design
    - M5 power connectors
    - High level of integration

#### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V <sub>DSS</sub>	Drain - Source Breakdown Voltage		1000	V
Т	Continuous Drain Current	$T_c = 25^{\circ}C$	78	
I <sub>D</sub>	Continuous Drain Current	$T_c = 80^{\circ}C$	59	А
I <sub>DM</sub>	Pulsed Drain current	312		
V <sub>GS</sub>	Gate - Source Voltage		±30	V
R <sub>DSon</sub>	Drain - Source ON Resistance		105	mΩ
P <sub>D</sub>	Maximum Power Dissipation	$T_c = 25^{\circ}C$	1250	W
I <sub>AR</sub>	Avalanche current (repetitive and non repetitive)		25	А
E <sub>AR</sub>	Repetitive Avalanche Energy		50	mJ
E <sub>AS</sub>	Single Pulse Avalanche Energy		3000	IIIJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1000V$	$T_j = 25^{\circ}C$			400		
		$V_{GS} = 0V, V_{DS} = 800V$	$T_j = 125^{\circ}C$			2000	μA	
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 39A$			90	105	mΩ	
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 10 \text{mA}$		3		5	V	
I <sub>GSS</sub>	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	r			±250	nA	

### **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C <sub>iss</sub>	Input Capacitance	$V_{GS} = 0V$		20.7		
Coss	Output Capacitance	$V_{\rm DS} = 25 V$		3.5		nF
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1MHz		0.64		
Qg	Total gate Charge	$V_{GS} = 10V$		744		nC
Q <sub>gs</sub>	Gate – Source Charge	$V_{Bus} = 500V$		96		
$Q_{gd}$	Gate – Drain Charge	$I_D = 78A$		488		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive switching @ 125°C $V_{GS} = 15V$ $V_{Bus} = 670V$ $I_D = 78A$ $R_G = 1.2\Omega$		18		ns
Tr	Rise Time			12		
T <sub>d(off)</sub>	Turn-off Delay Time			155		
$T_{\rm f}$	Fall Time			40		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$ , $V_{Bus} = 670V$ $I_D = 78A$ , $R_G = 1.2\Omega$		3.6		T.
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy			2.5		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V$ , $V_{Bus} = 670V$ $I_D = 78A$ , $R_G = 1.2\Omega$		5.7		J
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy			3.1		mJ

### Source - Drain diode ratings and characteristics

Symbol	Characteristic	<b>Test Conditions</b>		Min	Тур	Max	Unit
Is	Continuous Source current		$Tc = 25^{\circ}C$			78	А
	(Body diode)		$Tc = 80^{\circ}C$			59	Л
$V_{SD}$	Diode Forward Voltage	$V_{GS} = 0V, I_S = -78A$				1.3	V
dv/dt	Peak Diode Recovery <b>1</b>					10	V/ns
t <sub>rr</sub>	Reverse Recovery Time	$I_{\rm S} = -78 {\rm A}, {\rm V}_{\rm R} = 670 {\rm V}$			1170		ns
Q <sub>rr</sub>	Reverse Recovery Charge	$di_{s}/dt = 400A/\mu s$			65.1		μC

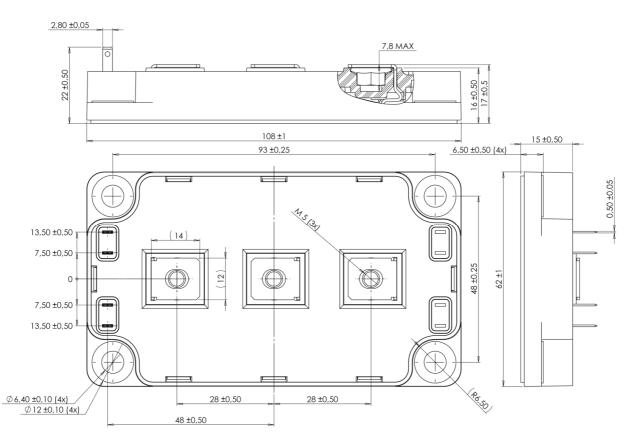
• dv/dt numbers reflect the limitations of the circuit rather than the device itself.  $I_S \le -78A$  di/dt  $\le 700A/\mu s$   $V_R \le V_{DSS}$   $T_i \le 150^{\circ}C$ 



### Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R <sub>thJC</sub>	Junction to Case Thermal Resistance					0.1	°C/W
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
TJ	Operating junction temperature range			-40		150	°C
T <sub>STG</sub>	Storage Temperature Range			-40		125	
T <sub>C</sub>	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	19.111
Wt	Package Weight					300	g

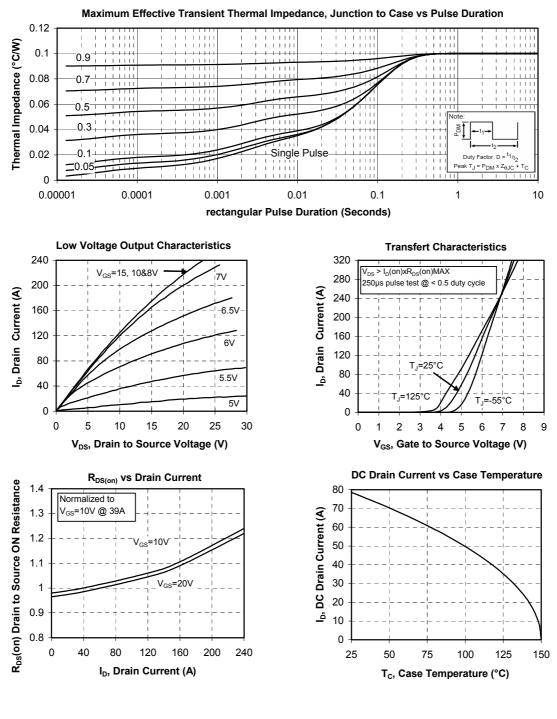
#### SP6 Package outline (dimensions in mm)



See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

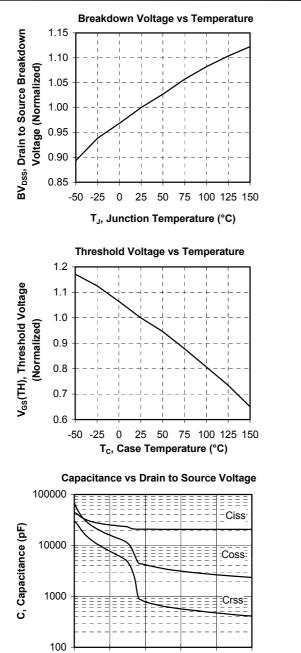


#### **Typical Performance Curve**



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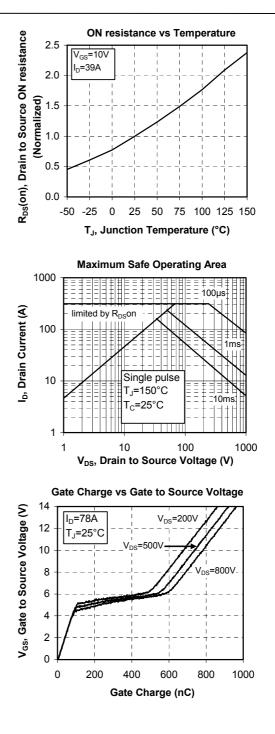
V<sub>DS</sub>, Drain to Source Voltage (V)

30

50

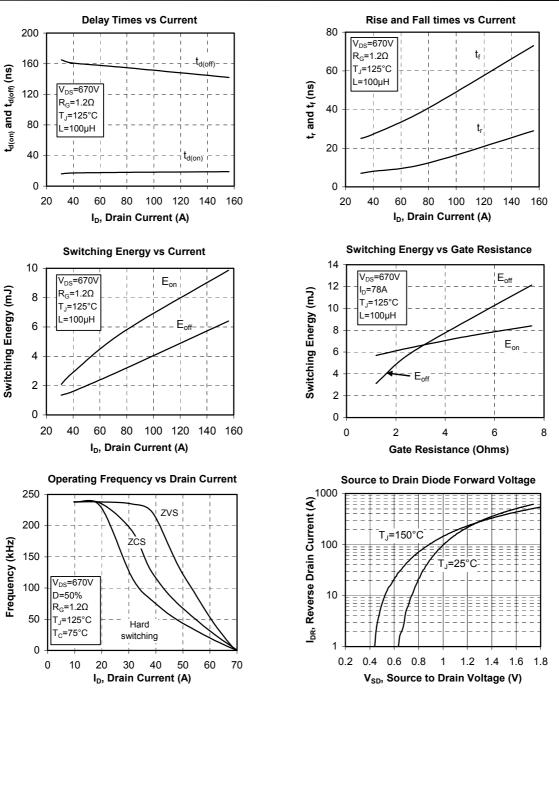
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### APTM100DUM90G



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